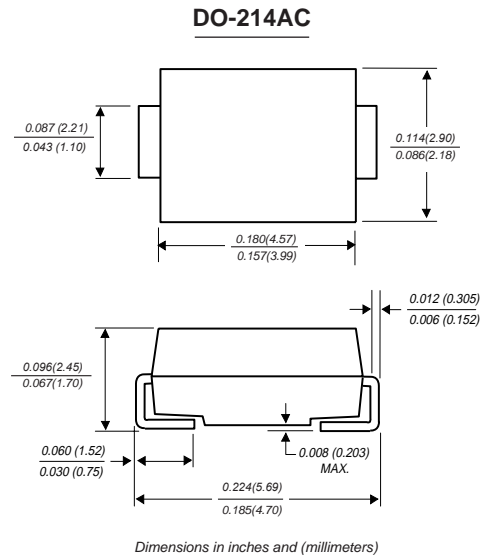


SURFACE MOUNT REVERSE VOLTAGE -20 to 100 Volts**SCHOTTKY BARRIER RECTIFIERS FORWARD CURRENT -5.0 Amperes****FEATURES**

- Metal-Semiconductor junction with gard ring
- Epitaxial construction
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0
- For use in low vlotage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: Molded Plastic
- Polarity:Color band denotes cathode

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

CHARACTERISTICS	SYMBOL	SS52	SS53	SS54	SS55	SS56	SS58	SS510	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	80	100	V
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	56	70	V
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Lengths	I _(AV)	5.0							A
Peak Forward Surage Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load(JEDEC Method)	I _{FSM}	100							A
Maximum Forward Voltage at 5.0A DC	V _F	0.55	0.6	0.7	0.85				V
Maximum DC Reverse Current @T _J =25°C at Rated DC Bolcking Voltage @T _J =100°C	I _R	1.0				50			mA
Typical Junction Capacitance (Note1)	C _J	500			350			pF	
Typical Thermal Resistance (Note2)	R _{θJA}	15			10			°C/W	
Operating Temperature Range	T _J	-55 to +150							°C
Storage Temperature Range	T _{STG}	-55 to +150							°C

NOTES: 1.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC

2.Thermal resistance junction to ambient,

FIG. 1 – FORWARD CURRENT DERATING CURVE

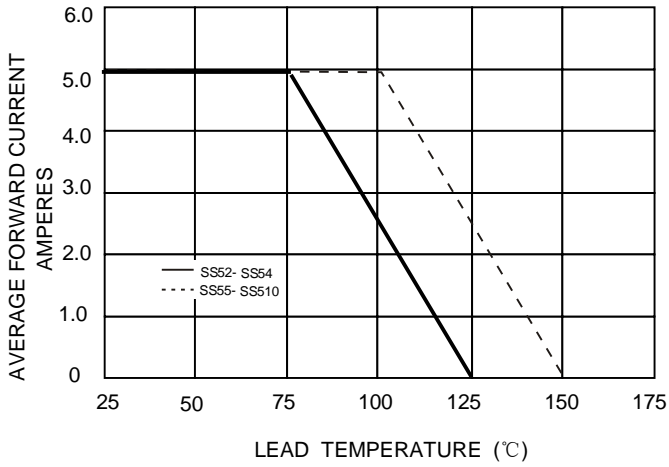


FIG. 2 – MAXIMUM NON-REPETITIVE SURGE CURRENT

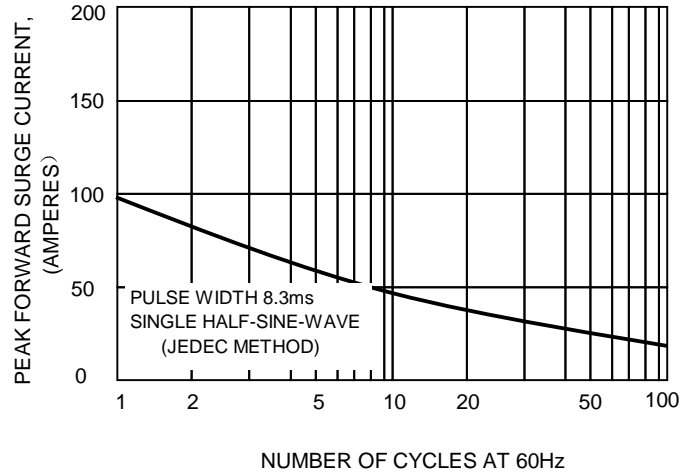


FIG.3 – TYPICAL JUNCTION CAPACITANCE

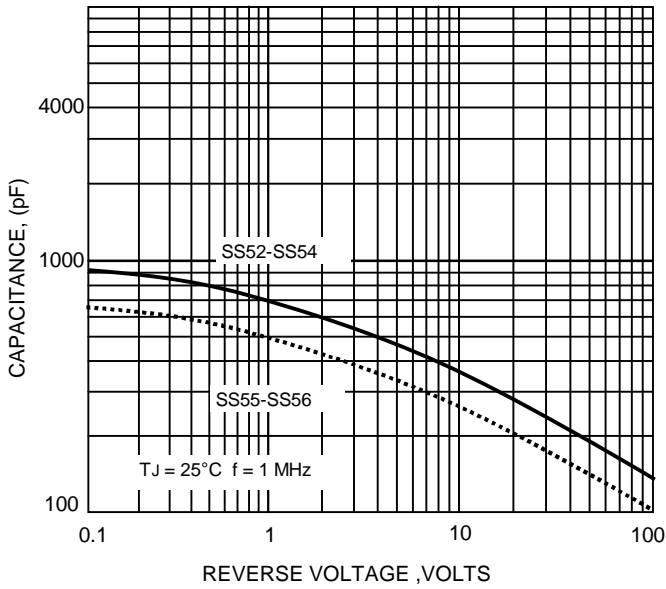


FIG.4-TYPICAL FORWARD CHARACTERISTICS

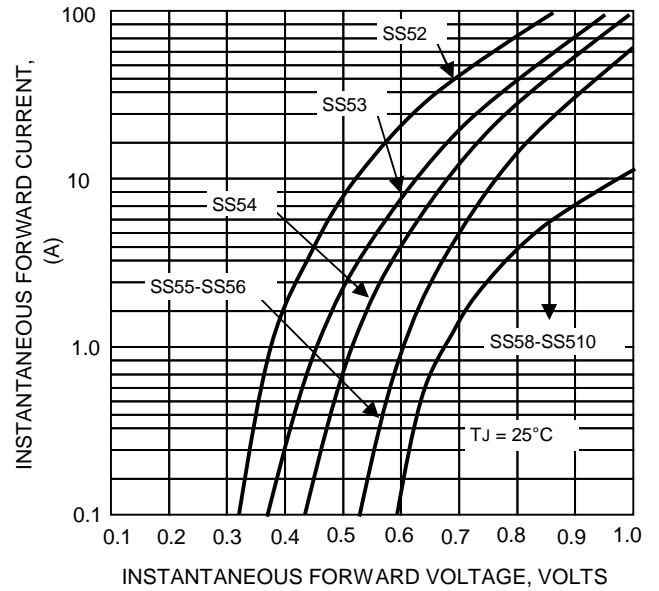


FIG.2-TYPICAL REVER CHARACTERISTICS

